

BYV32-200

SWITCHMODE™ Power Rectifier

... designed for use in switching power supplies, inverters and as free wheeling diodes, this state-of-the-art device has the following features:

- Ultrafast 35 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL94, V_O @ 1/8"
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: BYV32-200

MAXIMUM RATINGS

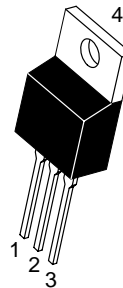
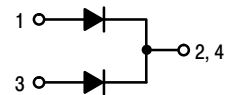
Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	200	Volts
Average Rectified Forward Current Total Device, (Rated V_R), $T_C = 150^\circ\text{C}$ Per Leg Total Device	$I_{F(AV)}$	8.0 16	Amps
Peak Rectified Forward Current (Rated V_R , Square Wave, 20 kHz), $T_C = 150^\circ\text{C}$ - Per Diode Leg	I_{FM}	16	Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	100	Amps
Operating Junction Temperature and Storage Temperature	T_J, T_{stg}	-65 to +175	°C



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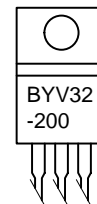
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**ULTRAFAST
RECTIFIER
16 AMPERES
200 VOLTS**



TO-220AB
CASE 221A
PLASTIC

MARKING DIAGRAM



BYV32-200 = Device Code

ORDERING INFORMATION

Device	Package	Shipping
BYV32-200	TO-220	50 Units/Rail

BYV32-200

THERMAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.0	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 5.0$ Amps, $T_C = 100^{\circ}C$) ($i_F = 20$ Amps, $T_C = 25^{\circ}C$)	V_F	0.85 1.15	Volts
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 100^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$)	i_R	600 50	μA
Maximum Reverse Recovery Time ($I_F = 1.0$ Amp, $di/dt = 50$ Amps/ μs) ($I_F = 0.5$ Amp, $I_R = 1.0$ Amp, $I_{REC} = 0.25$ Amp)	t_{rr}	35 25	ns

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$

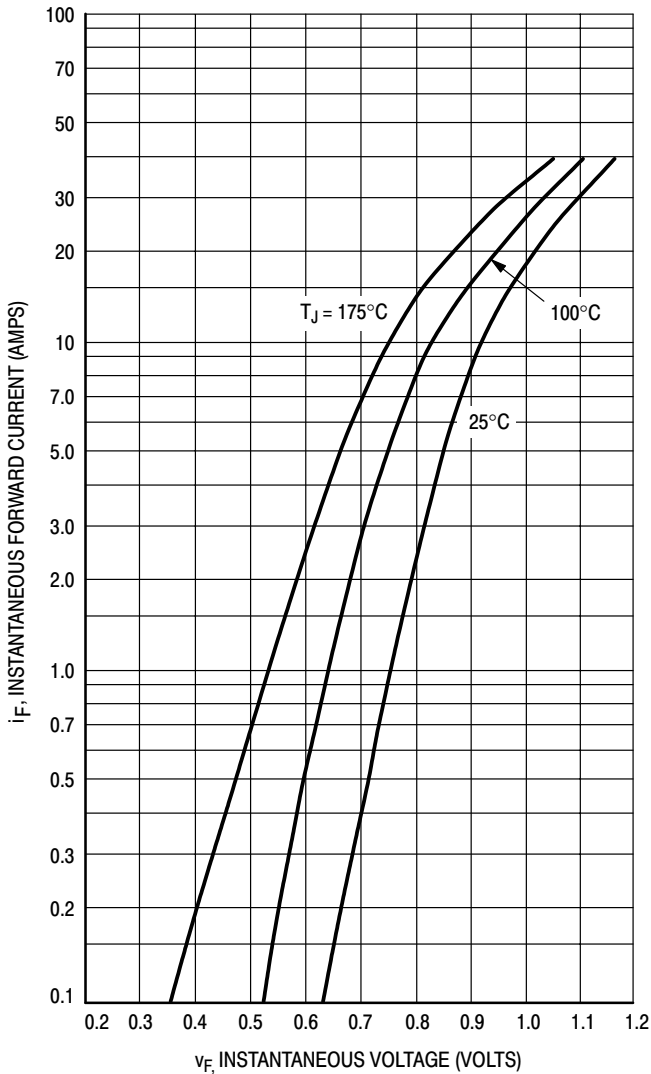


Figure 1. Typical Forward Voltage, Per Leg

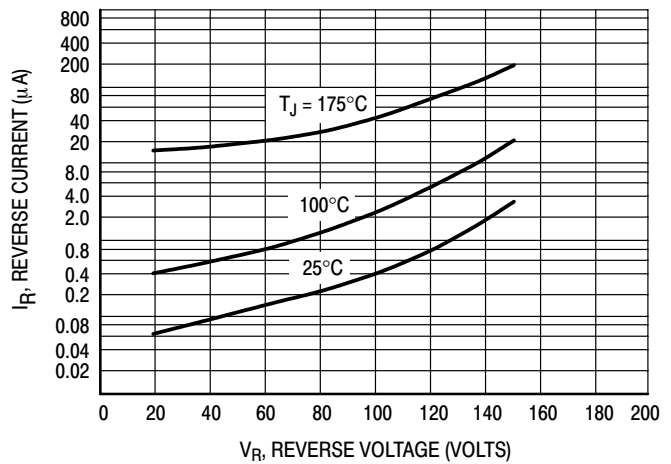


Figure 2. Typical Reverse Current, Per Leg*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_R is sufficiently below rated V_R .

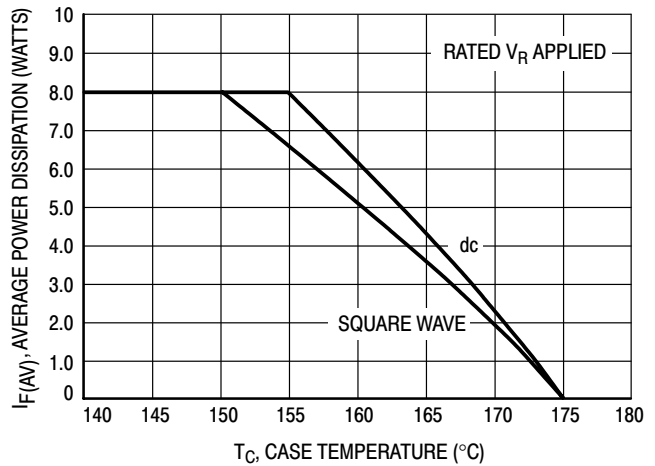


Figure 3. Current Derating, Case, Per Leg

BYV32-200

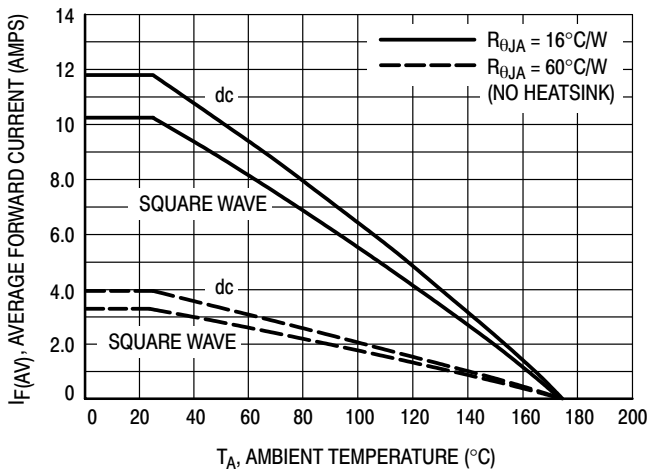


Figure 4. Current Derating, Ambient, Per Leg

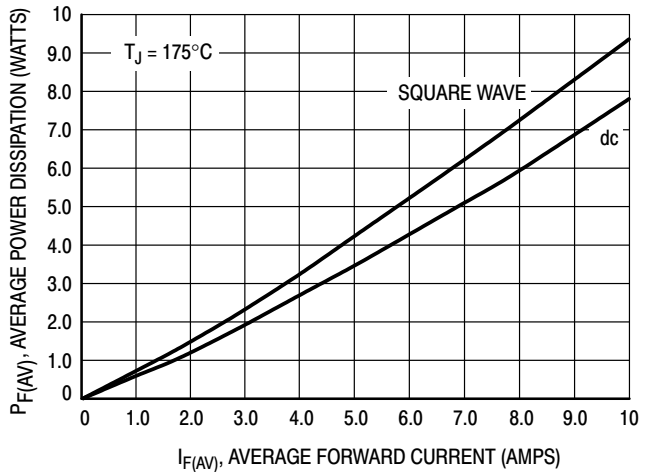


Figure 5. Power Dissipation, Per Leg

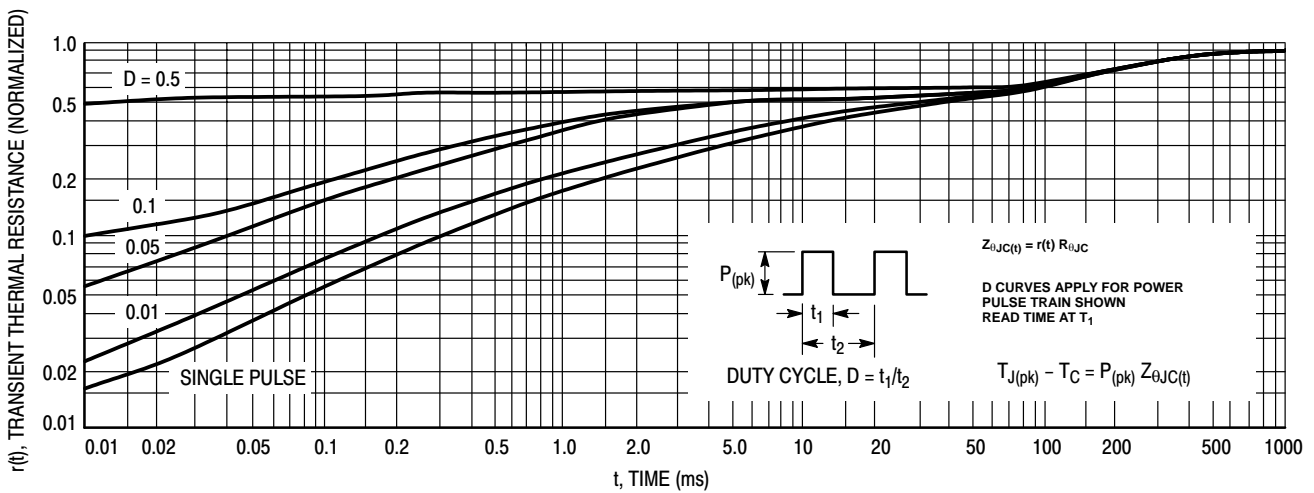


Figure 16. Thermal Response

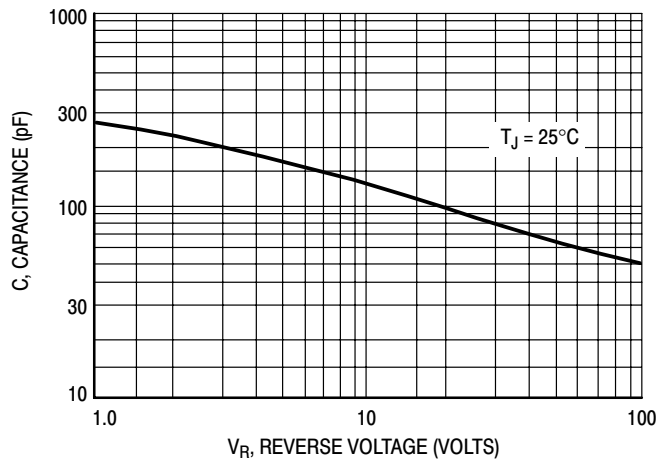
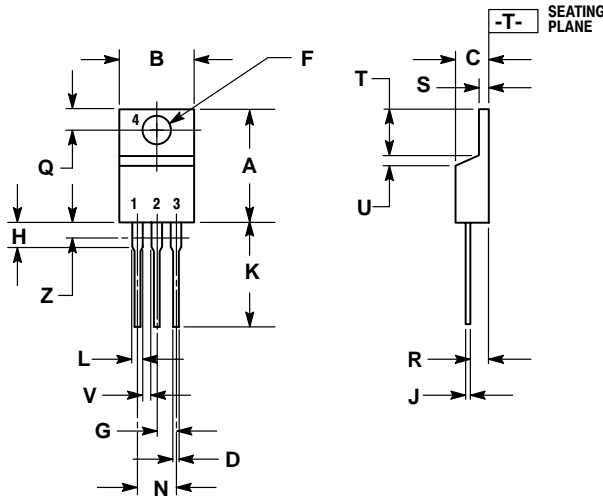


Figure 17. Typical Capacitance, Per Leg

BYV32-200

PACKAGE DIMENSIONS

TO-220 THREE-LEAD TO-220AB CASE 221A-09 ISSUE AA




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

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